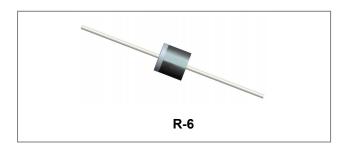






20SQ045-1 SCHOTTKY BARRIER RECTIFIER



Features

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- DC-DC converters
- AC adapter
- · High frequency rectification circuit
- Bypass diodes
- Photovoltaic Solar cell Protection Schottky Rectifier

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _A = 25°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	350	Α

Electrical Characteristics:

Characteristics	Symbol	Condition		Тур.	Max.	Units
Peak Forward Voltage	V _{FM}	I _{FM} =20.0A,Ta=25°	C	0.48	0.55	V
Peak Reverse Current	I _{RRM1}	\/ -\/	Ta=25℃	0.07	0.5	mA
	I _{RRM2}	$V_{RM}=V_{RRM}$	Ta=100℃	-	50	
Thermal Resistance	R _{θJ-c}	Between junction and case		3.0	-	°C/W
	R _{θJ-L}	Between junction and lead		2.0	-	

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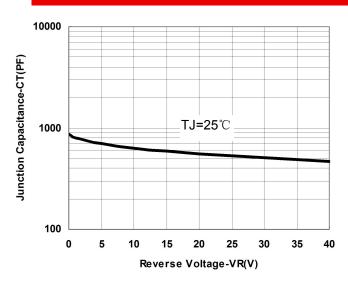




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	Vr≪80%Vrrm Vr≪50%Vrrm	-55 to +150 -55 to +180 -55 to +200	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Approximate Weight	wt	-	2.24	g
Case Style	R-6			

Ratings and Characteristics Curves



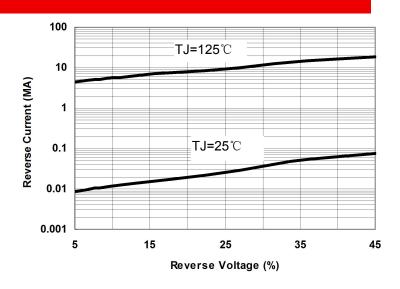


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

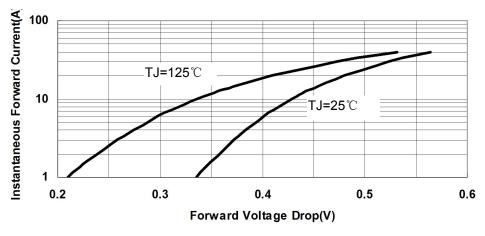


Fig.3-Typical Instantaneous Forward Voltage Characteristics

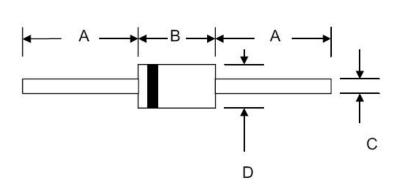
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Mechanical Dimensions R-6



SYMBOL	Millim	neters	Inches		
STMBOL	Min.	in. Max. Mi		Max.	
А	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

Ordering Information

Device	Package	Shipping		
20SQ045	R-6(Pb-Free)	500pcs / reel		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

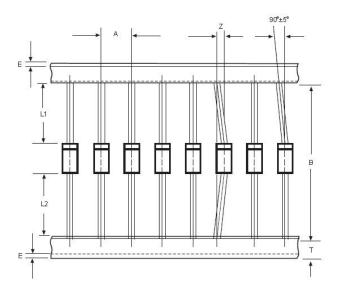


Where XXXXX is YYWWL

20 = Forward Current (20A)
S = Package Type
Q = Device Type
045 = Reverse Voltage (45V)

-1 = -1 SSG = SSG YY = Year WW = Week L = Lot Number

Carrier Tape Specification R-6



SYMBOL	Millimeters			
STWIBOL	Min.	Max.		
А	9.50	10.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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